



SPECIFICATION

- Supplier : Samsung electro-mechanics
- Product : Multi-layer Ceramic Capacitor
- Samsung P/N : CL10C100CB8NNND
- Description : CAP, 10pF, 50V, ±0.25pF, C0G, 0603

A. Samsung Part Number

		-	<u>CL 10</u> ① ②	<u>C</u> 3	<u>100</u> ④	<u>C</u> 5	<u>B</u> 6	<u>8</u> 1	<u>N</u> 8	<u>N</u> 9	<u>N</u> 10	<u>D</u> 10	
1	Series	Samsung Multi-layer Ceramic Capacitor											
2	Size	0603 (ind	ch code)		L:	1.6	± 0.1		mm		W:	0.8 ± 0.1	mm
3 4	Dielectric Capacitance	C0G 10 pF				-	Inner Term			e		Ni Cu	
5	Capacitance	±0.25 pF					Plati	ng				Sn 100%	(Pb Free)
	tolerance					9	Prod	uct				Normal	
6	Rated Voltage	50 V				10	Spec	ial				Reserved for	future use
\bigcirc	Thickness	0.8 ± 0	.1 mm			1	Pack	agir	ng			Cardboard T	ype,13"reel(10,000ea)

B. Samsung Reliability Test and Judgement condition

	Performance	Test condition						
Capacitance	Within specified tolerance	1M±10% 0.5~5Vrms						
Q	600 min							
Insulation	More than 500Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.						
Resistance								
Appearance	No abnormal exterior appearance	Visual inspection						
Withstanding	No dielectric breakdown or	300% of the rated voltage						
Voltage	mechanical breakdown							
Temperature	C0G							
Characteristics	(From -55℃ to 125℃, Capacitance change should be within ±30PPM/℃)							
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.						
of Termination	terminal electrode							
Bending Strength	Capacitance change : within ±5%	Bending to the limit (1mm)						
		with 1.0mm/sec.						
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder						
	is to be soldered newly	245±5℃, 3±0.3sec.						
		(preheating : 80~120 ℃ for 10~30sec.)						
Resistance to	Capacitance change : within ±2.5%	Solder pot : 270±5℃, 10±1sec.						
Soldering heat	Tan δ, IR : initial spec.							

	Performance	Test condition					
Vibration Test	Capacitance change : within ±2.5%	Amplitude : 1.5mm					
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)					
		2hours \times 3 direction (x, y, z)					
Moisture	Capacitance change : within ±7.5%	With rated voltage					
Resistance	Q : 133.33 min	40±2℃, 90~95%RH, 500 +12/-0 hour					
	IR : More than 25MΩ·μF						
High Temperature	Capacitance change : within ±3%	With 200% of the rated voltage					
Resistance	Q : 300 min	Max. operating temperature					
	IR : More than 50MΩ· μF	1000+48/-0 hour					
Temperature	Capacitance change : within ±2.5%	1 cycle condition					
Cycling	Tan δ, IR : initial spec.	Min. operating temperature \rightarrow 25 °C					
		\rightarrow Max. operating temperature \rightarrow 25 °C					
		5 cycles test					

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5°C, 10sec. Max)

* For the more detail Specification, Please refer to the Samsung MLCC catalogue.